

## Very low capacitance ESD protection

Datasheet - production data

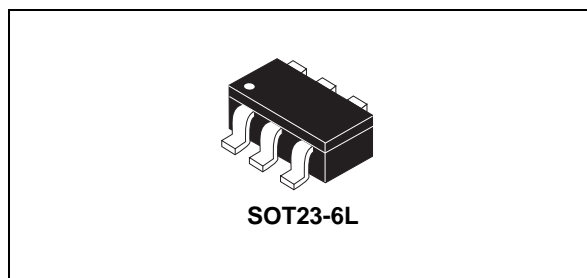
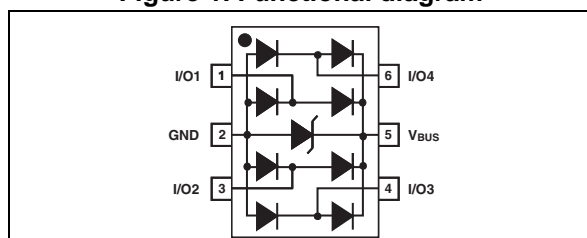


Figure 1. Functional diagram



### Features

- 4 data-line protection
- Protects  $V_{BUS}$
- Very low capacitance: 3 pF typ.
- Peak pulse power (8/20  $\mu$ s): 130 W typ.
- SOT23-6L package
- RoHS compliant

### Benefits

- Very low capacitance between lines to GND for optimized data integrity and speed
- Low PCB space consumption, 9 mm<sup>2</sup> maximum foot print
- Enhanced ESD protection: IEC 61000-4-2 level 4 compliance guaranteed at device level, hence greater immunity at system level
- ESD protection of  $V_{BUS}$ : allows ESD current flowing to ground when ESD event occurs on data line
- High reliability offered by monolithic integration

- Low leakage current for longer operation of battery powered devices
- Fast response time
- Consistent D+ / D- signal balance:
  - Best capacitance matching tolerance I/O to GND = 0.015 pF
  - Compliant with USB 2.0 requirements < 1 pF

### Complies with the following standards

- IEC 61000-4-2 level 4:
  - 15 kV (air discharge)
  - 8 kV (contact discharge)

### Applications

- USB 2.0 ports up to 480 Mb/s (high speed)
- Backwards compatible with USB 1.1 low and full speed
- Ethernet port: 10/100 Mb/s
- SIM card protection
- Video line protection
- Portable electronics

### Description

The USBLC6-4 is a monolithic application specific device dedicated to ESD protection of high speed interfaces, such as USB 2.0, Ethernet links and video lines.

Its very low line capacitance secures a high level of signal integrity without compromising in protecting sensitive chips against the most stringent characterized ESD strikes.

# 1 Characteristics

**Table 1. Absolute ratings**

Symbol	Parameter		Value	Unit
$V_{PP}$	Peak pulse voltage	IEC 61000-4-2 air discharge	15	kV
		IEC 61000-4-2 contact discharge	15	
		MIL STD883C-Method 3015-6	25	
$T_{stg}$	Storage temperature range		-55 to +150	°C
$T_j$	Operating junction temperature range		-40 to +125	°C
$T_L$	Lead solder temperature (10 seconds duration)		260	°C

**Table 2. Electrical characteristics ( $T_{amb} = 25\text{ °C}$ )**

Symbol	Parameter	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
$I_{RM}$	Leakage current	$V_{RM} = 5.25\text{ V}$		10	150	nA
$V_{BR}$	Breakdown voltage between $V_{BUS}$ and GND	$I_R = 1\text{ mA}$	6		10	V
$V_F$	Forward voltage	$I_F = 10\text{ mA}$			0.86	V
$V_{CL}$	Clamping voltage	$I_{PP} = 1\text{ A}$ , 8/20 $\mu\text{s}$ Any I/O pin to GND			12	V
		$I_{PP} = 5\text{ A}$ , 8/20 $\mu\text{s}$ Any I/O pin to GND			17	V
$C_{i/o-GND}$	Capacitance between I/O and GND	$V_R = 1.65\text{ V}$		3	4	pF
$\Delta C_{i/o-GND}$				0.015		
$C_{i/o-i/o}$	Capacitance between I/O	$V_R = 1.65\text{ V}$		1.85	2.7	pF
$\Delta C_{i/o-i/o}$				0.04		

Figure 2. Capacitance versus voltage  
(typical values)

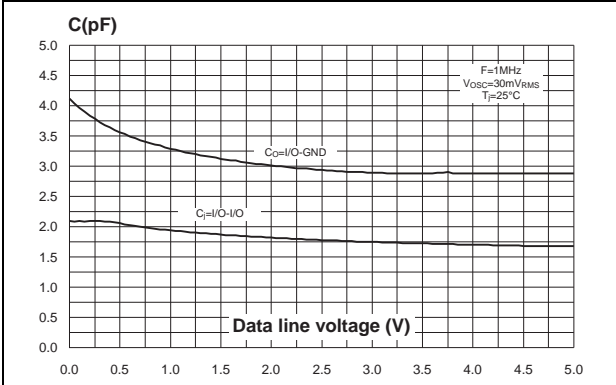


Figure 3. Line capacitance versus frequency  
(typical values)

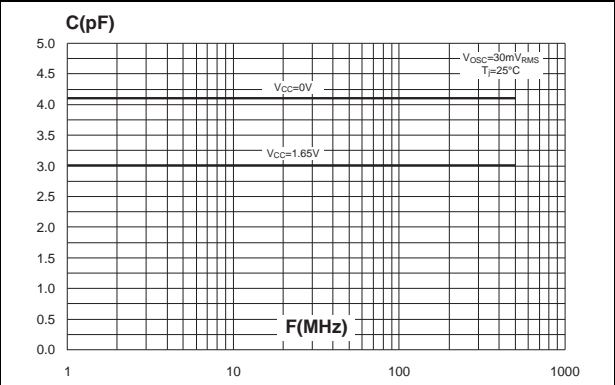


Figure 4. Relative variation of leakage current  
versus junction temperature (typical values)

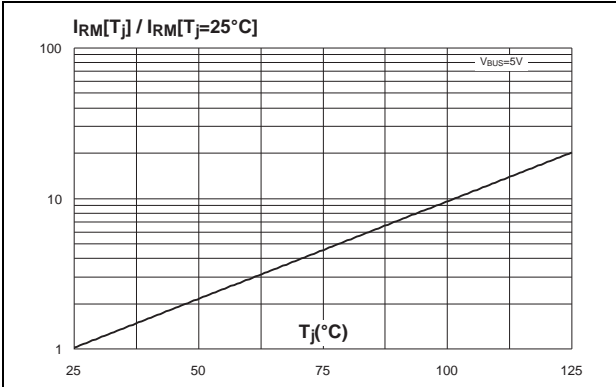
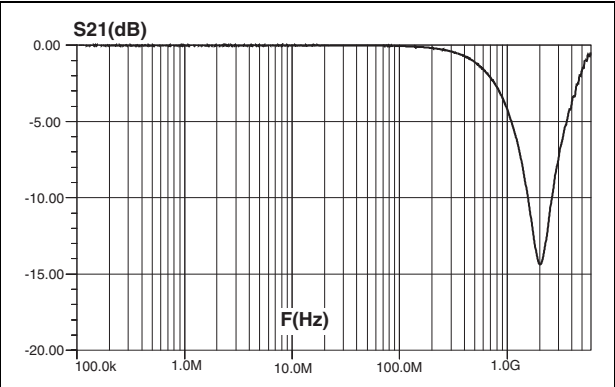


Figure 5. Frequency response



## 2 Technical information

### 2.1 Surge protection

The USBLC6-4SC6 is particularly optimized to provide surge protection based on the rail to rail topology.

The clamping voltage  $V_{CL}$  can be calculated as follows:

$$V_{CL+} = V_{TRANSIL} + V_F \text{ for positive surges}$$

$$V_{CL-} = -V_F \text{ for negative surges}$$

$$\text{with: } V_F = V_T + R_d \cdot I_p$$

( $V_F$  forward drop voltage,  $V_T$  forward drop threshold voltage)

#### Calculation example

We assume that the value of the dynamic resistance of the clamping diode is typically:

$$R_d = 0.5 \, \Omega \text{ and } V_T = 1.1 \, \text{V.}$$

For an IEC 61000-4-2 surge level 4 (Contact Discharge:  $V_g = 8 \, \text{kV}$ ,  $R_g = 330 \, \Omega$ ),  $V_{BUS} = +5 \, \text{V}$ , and if in a first approximation, we assume that:

$$I_p = V_g / R_g = 24 \, \text{A.}$$

So, we find:

$$V_{CL+} = +31.2 \, \text{V}$$

$$V_{CL-} = -13.1 \, \text{V}$$

*Note: The calculations do not take into account phenomena due to parasitic inductances.*

### 2.2 Surge protection application example

If we consider that the connections from the pin  $V_{BUS}$  to  $V_{CC}$ , from I/O to data line and from GND to PCB GND plane are implemented as racks 10 mm long and 0.5 mm large, we can assume that the parasitic inductances  $L_{VBUS}$ ,  $L_{I/O}$  and  $L_{GND}$  of these tracks are about 6 nH. So, when an IEC 61000-4-2 surge occurs, due to the rise time of this spike ( $t_r = 1 \, \text{ns}$ ), the voltage  $V_{CL}$  has an extra value equal to  $L_{I/O} \cdot dI/dt$ , +  $L_{GND} \cdot dI/dt$

The  $dI/dt$  is calculated as:

$$dI/dt = I_p/t_r = 24 \, \text{A/ns}$$

The overvoltage due to the parasitic inductances is:

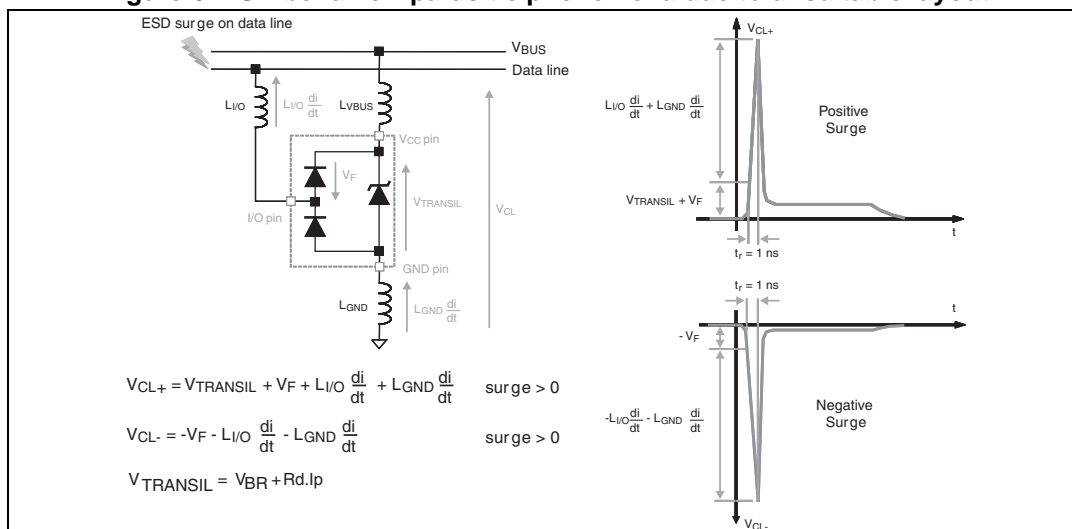
$$L_{I/O} \cdot dI/dt, = L_{GND} \cdot dI/dt = 6 \times 24 = 144 \, \text{V}$$

By taking into account the effect of these parasitic inductances due to unsuitable layout, the clamping voltage will be:

$$V_{CL+} = +31.2 + 144 + 144 = 319.2 \, \text{V}$$

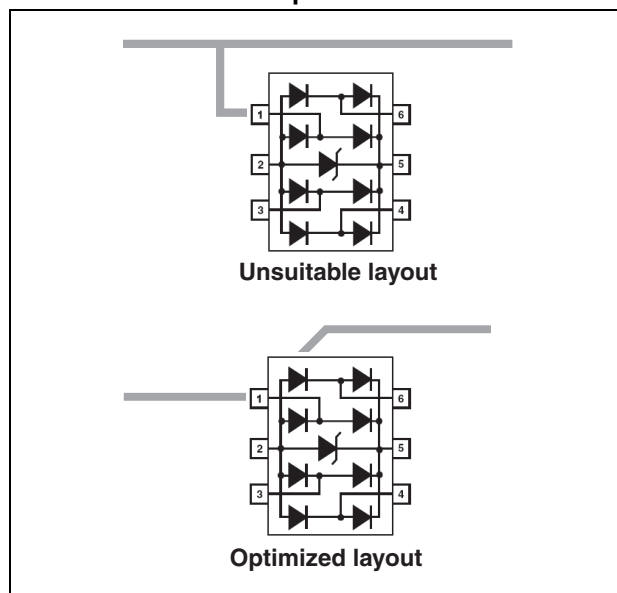
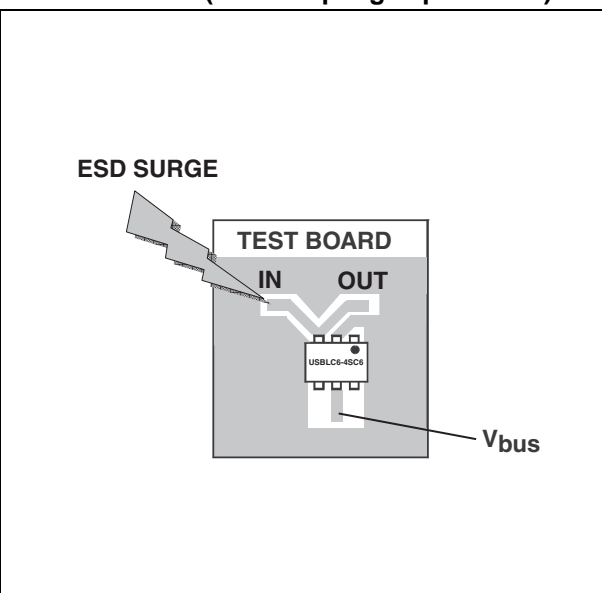
$$V_{CL-} = -13.1 - 144 - 144 = -301.1 \, \text{V}$$

We can significantly reduce this phenomena with simple layout optimization. It is for this reason that some recommendations have to be followed (see [2.3: How to ensure good ESD protection](#)).

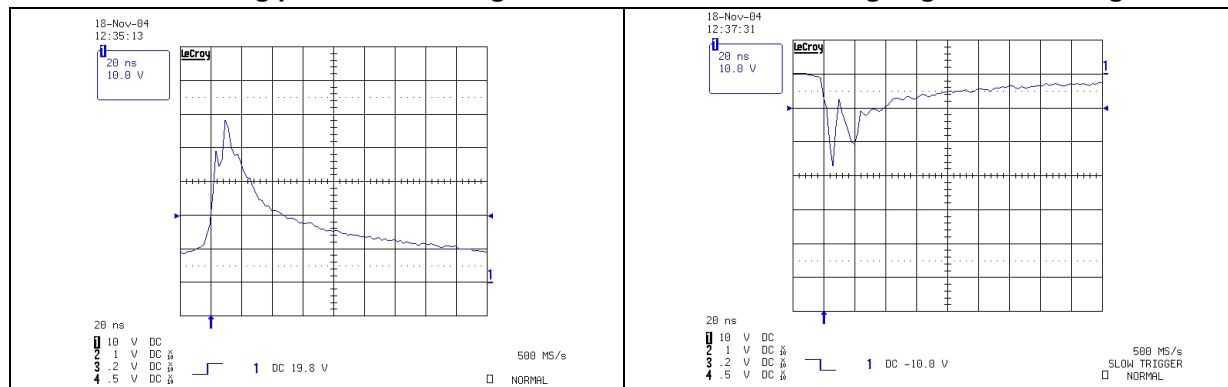
**Figure 6. ESD behavior: parasitic phenomena due to unsuitable layout**

## 2.3 How to ensure good ESD protection

While the USBLC6-4SC6 provides high immunity to ESD surge, efficient protection depends on the layout of the board. In the same way, with the rail to rail topology, the track from data lines to I/O pins, from V<sub>CC</sub> to the V<sub>BUS</sub> pin and from GND plane to GND pin must be as short as possible to avoid overvoltages due to parasitic phenomena (see [Figure 7](#) and [Figure 8](#) for layout considerations)

**Figure 7. ESD behavior: optimized layout and addition of a capacitance of 100 nF****Figure 8. ESD behavior: measurement conditions (with coupling capacitance)**

**Figure 9. Remaining voltage after the USBLC6-4SC6 during positive ESD surge**      **Figure 10. Remaining voltage after the USBLC6-4SC6 during negative ESD surge**



**Note:** The measurements have been done with the USBLC6-4SC6 in open circuit.

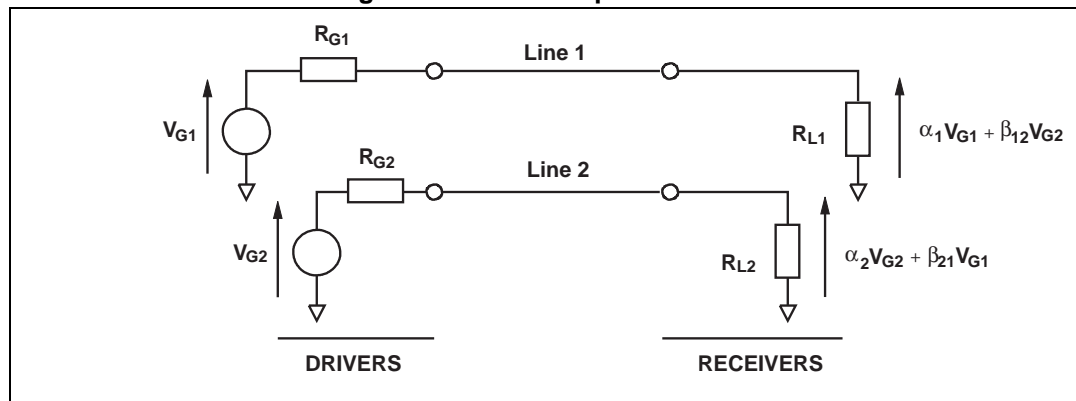
### Important:

A good precaution to take is to put the protection device as close as possible to the disturbance source (generally the connector).

## 2.4 Crosstalk behavior

### 2.4.1 Crosstalk phenomenon

**Figure 11. Crosstalk phenomenon**



The crosstalk phenomenon is due to the coupling between 2 lines. The coupling factor ( $\beta_{12}$  or  $\beta_{21}$ ) increases when the gap across lines decreases, particularly in silicon dice. In the above example the expected signal on load  $R_{L2}$  is  $\alpha_2 V_{G2}$ , in fact the real voltage at this point has got an extra value  $\beta_{21} V_{G1}$ . This part of the  $V_{G1}$  signal represents the effect of the crosstalk phenomenon of the line 1 on the line 2. This phenomenon has to be taken into account when the drivers impose fast digital data or high frequency analog signals in the disturbing line. The perturbed line will be more affected if it works with low voltage signal or high load impedance (few k $\Omega$ ).

Figure 12. Analog crosstalk measurements

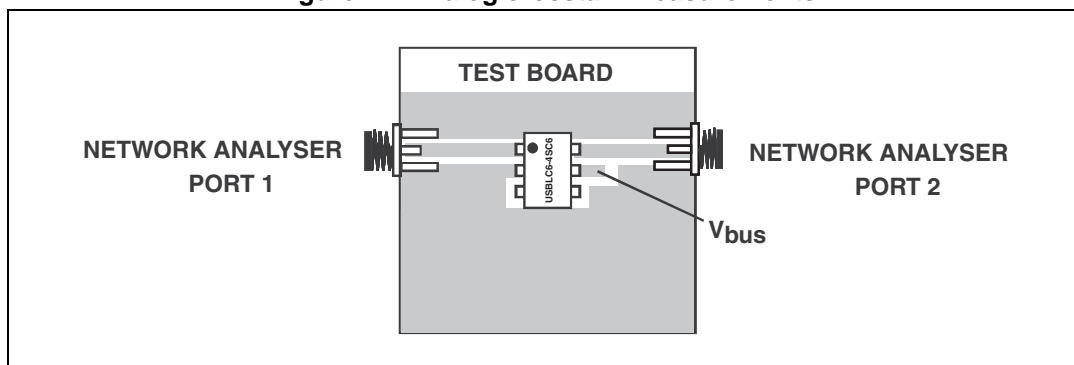
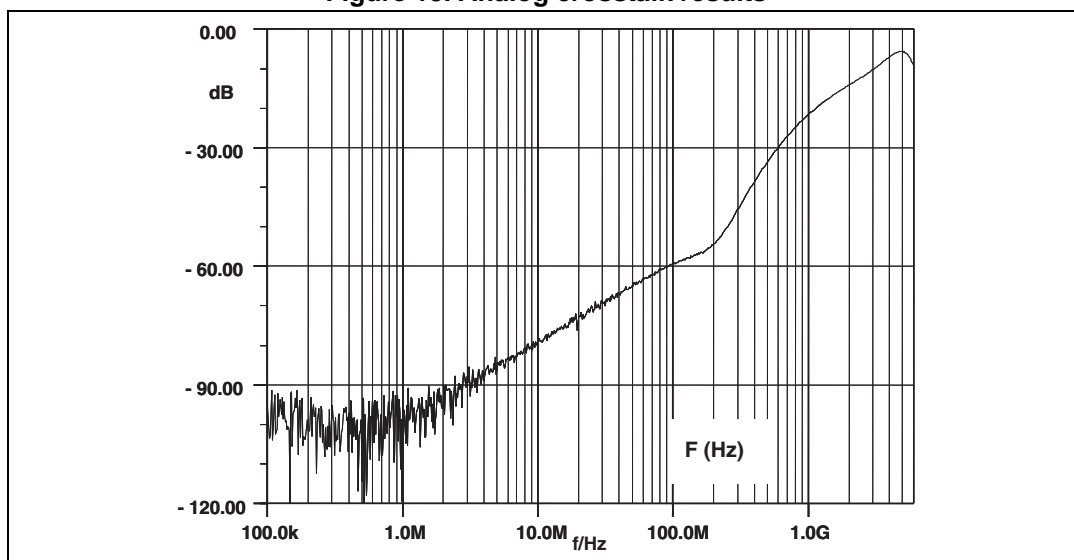


Figure 12. shows the measurement circuit for the analog application. In usual frequency range of analog signals (up to 240 MHz) the effect on disturbed line is less than -55 dB (see Figure 13.).

Figure 13. Analog crosstalk results



As the USBLC6-4SC6 is designed to protect high speed data lines, it must ensure a good transmission of operating signals. The frequency response (Figure 5.) gives attenuation information and shows that the USBLC6-4SC6 is well suitable for data line transmission up to 480 Mbit/s while it works as a filter for undesirable signals like GSM (900 MHz) frequencies, for instance.

## 2.5 Application examples

Figure 14. USB 2.0 port application diagram using USBLC6-4SC6

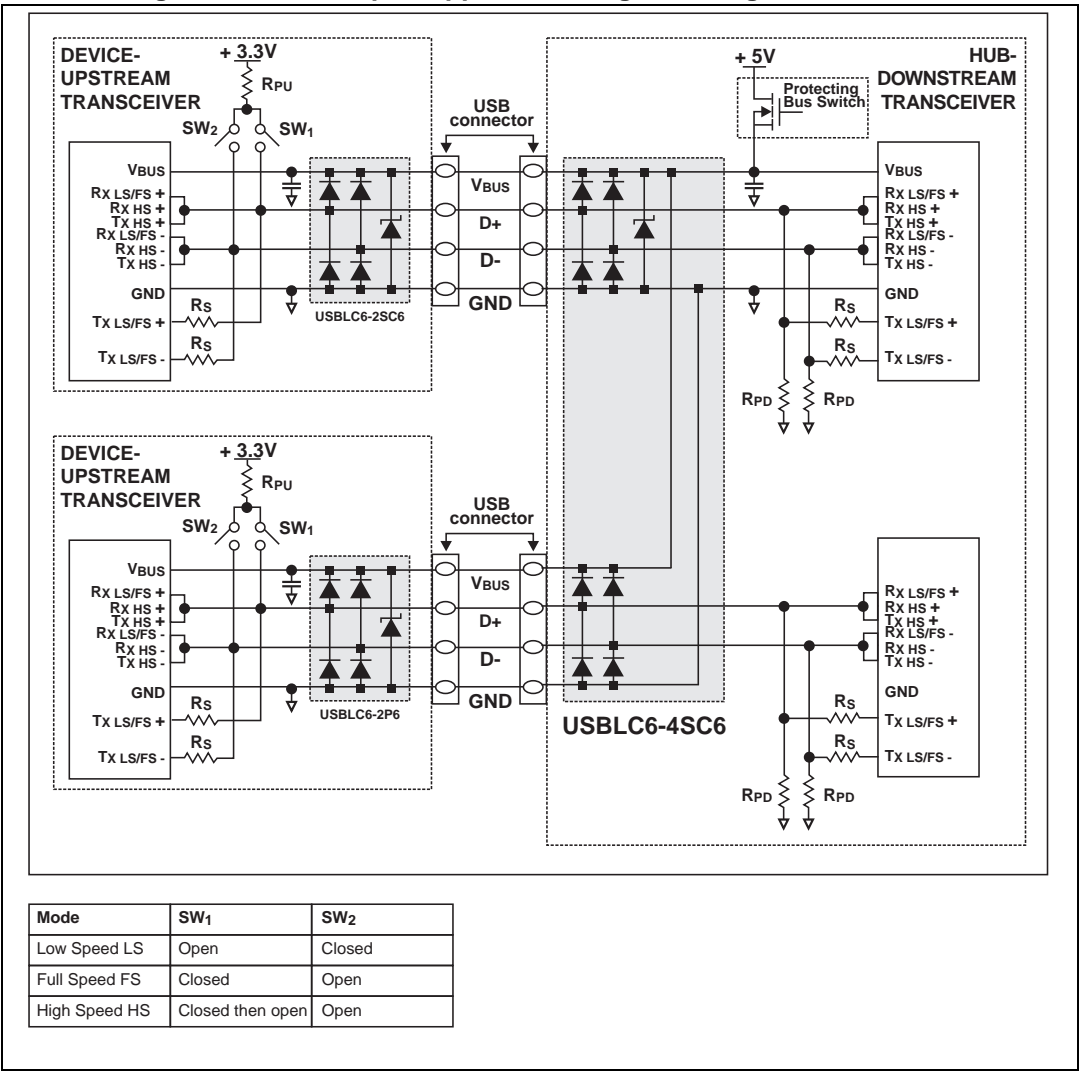
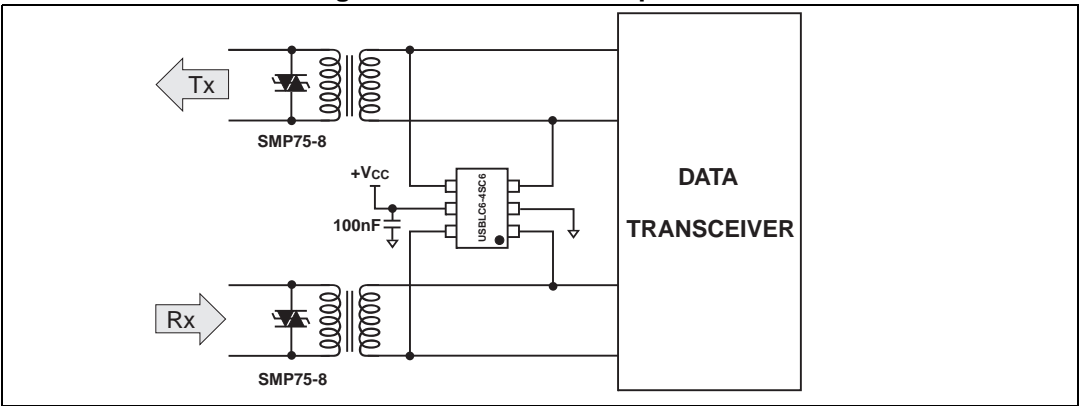


Figure 15. T1/E1/Ethernet protection

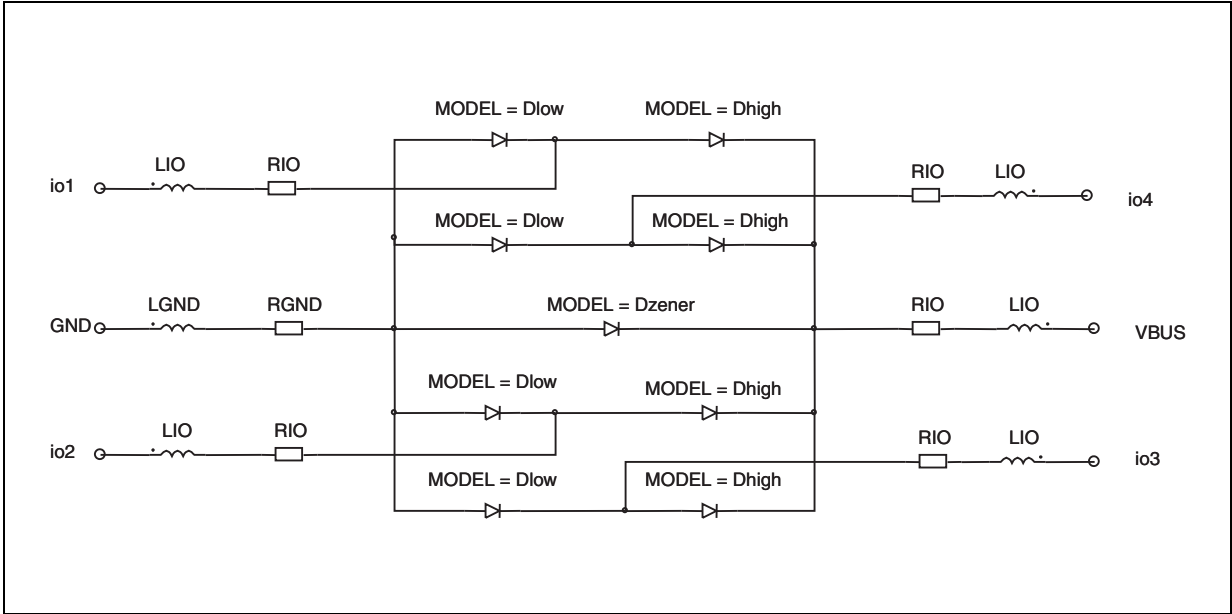




2.6 PSPICE model

Figure 16. shows the PSPICE model of one USBLC6-4SC6 cell. In this model, the diodes are defined by the PSPICE parameters given in Figure 17.

Figure 16. PSPICE model



Note: This simulation model is available only for an ambient temperature of 27 °C.

Figure 17. PSPICE parameters

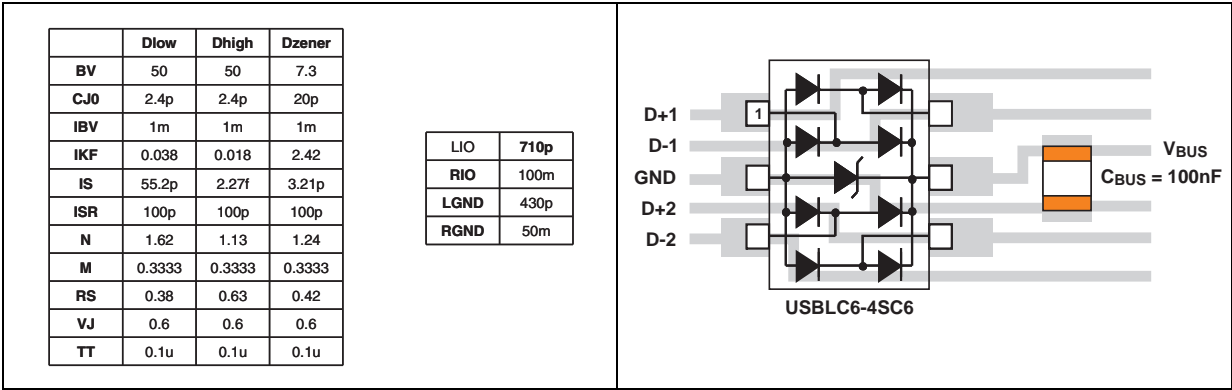
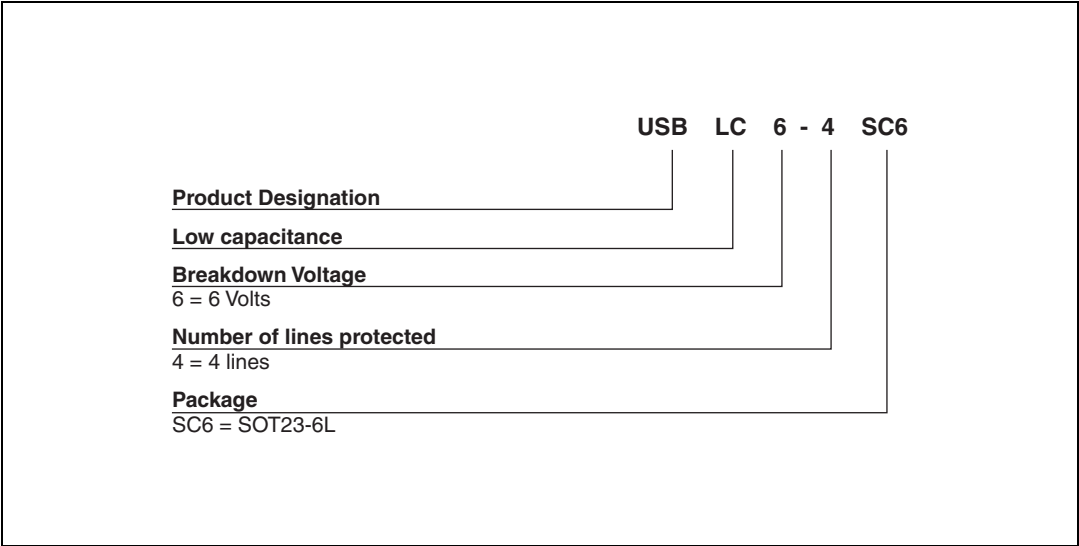


Figure 18. USBLC6-4SC6 PCB layout considerations

3      Ordering information scheme

Figure 19. Ordering information scheme



# 4 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

Table 3. SOT23-6L package dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.90		1.45	0.035		0.057
A1	0		0.10	0		0.004
A2	0.90		1.30	0.035		0.051
b	0.35		0.50	0.014		0.02
C	0.09		0.20	0.004		0.008
D	2.80		3.05	0.110		0.120
E	1.50		1.75	0.059		0.069
e		0.95			0.037	
H	2.60		3.00	0.102		0.118
L	0.10		0.60	0.004		0.024
θ	0°		10°	0°		10°

Figure 20. SOT23-6L footprint (mm)

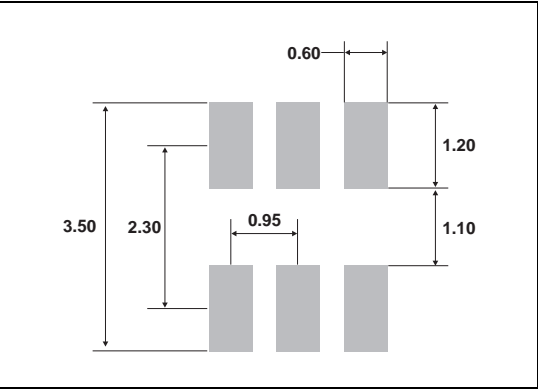
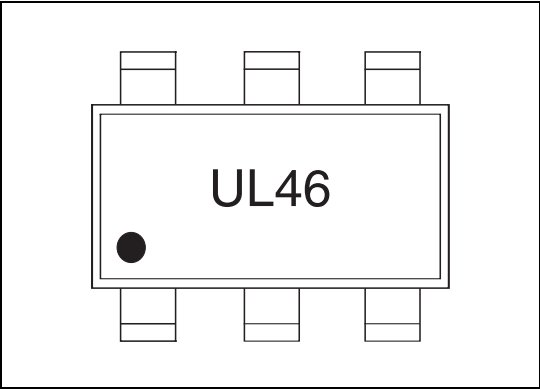


Figure 21. SOT23-6L marking



## 5 Ordering information

**Table 4. Ordering information**

Order code	Marking	Package	Weight	Base qty	Delivery mode
USBLC6-4SC6	UL46	SOT23-6L	16.7 mg	3000	Tape and reel

## 6 Revision history

**Table 5. Document revision history**

Date	Revision	Changes
10-Dec-2004	1	First issue.
28-Feb-2005	2	Minor layout update. No content change.
04-Feb-2008	3	Updated operating junction temperature range in absolute ratings, page 2. Updated Section 2: Technical information. Updated marking illustration Figure 21. Reformatted to current standard.
23-Sep-2011	4	Updated leakage current at $V_{RM} = 5.25$ V as specified in USB standard. Updated marking illustration Figure 21.
13-Oct-2015	5	Updated features in cover page and <a href="#">Table 2</a> .
26-Oct-2015	6	Updated features in cover page.
03-Nov-2015	7	Minor text changes.

**IMPORTANT NOTICE – PLEASE READ CAREFULLY**

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2015 STMicroelectronics – All rights reserved



# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[STMicroelectronics:](#)

[USBLC6-4SC6](#)